# **BTA216 series B**

## **GENERAL DESCRIPTION**

Glass passivated high commutation triacs in a plastic envelope intended for use in circuits where high static and dynamic dV/dt and high dl/dt can occur. These devices will commutate the full rated rms current at the maximum rated junction temperature, without the aid of a snubber.

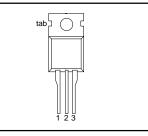
## QUICK REFERENCE DATA

**PIN CONFIGURATION** 

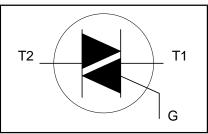
SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
V <sub>drm</sub> I <sub>t(rms)</sub> I <sub>tsm</sub>	BTA216- Repetitive peak off-state voltages RMS on-state current Non-repetitive peak on-state current	<b>500B</b> 500 16 140	<b>600B</b> 600 16 140	<b>800B</b> 800 16 140	V A A

## **PINNING - TO220AB**

PIN	DESCRIPTION
1	main terminal 1
2	main terminal 2
3	gate
tab	main terminal 2



## SYMBOL



## LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.		MAX.		UNIT
V <sub>drm</sub>	Repetitive peak off-state voltages		-	<b>-500</b> 500 <sup>1</sup>	<b>-600</b> 600 <sup>1</sup>	<b>-800</b> 800	>
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave;	-		16		A
I <sub>TSM</sub>	Non-repetitive peak on-state current	$T_{mb} \le 99 \ ^{\circ}C$ full sine wave; $T_j = 25 \ ^{\circ}C$ prior to surge t = 20 ms	_		140		A
		t = 16.7 ms	-		150		
l²t dI <sub>T</sub> /dt	I <sup>2</sup> t for fusing Repetitive rate of rise of on-state current after triggering		-		98 100		A²s A/μs
$\begin{matrix} I_{GM} \\ V_{GM} \\ P_{GM} \\ P_{G(AV)} \end{matrix}$	Peak gate current Peak gate voltage Peak gate power Average gate power	over any 20 ms			2 5 5 0.5		A V W W
T <sub>stg</sub> T <sub>j</sub>	Storage temperature Operating junction temperature	period	-40 -		150 125		°C °C

<sup>1</sup> Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15  $A/\mu s$ .

# BTA216 series B

## THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th i-a</sub>	Thermal resistance junction to mounting base Thermal resistance junction to ambient	full cycle half cycle in free air		- - 60	1.2 1.7 -	K/W K/W K/W

## STATIC CHARACTERISTICS

 $T_i = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
I <sub>GT</sub>	Gate trigger current <sup>2</sup>	$V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$					
01			T2+ G+	2	18	50	mA
			T2+ G-	2 2	21	50	mA
			T2- G-	2	34	50	mA
IL.	Latching current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$					
_	-		T2+ G+	-	31	60	mA
			T2+ G-	-	34	90	mA
			T2- G-	-	30	60	mA
I <sub>H</sub>	Holding current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$		-	31	60	mA
I <sub>H</sub> V <sub>T</sub> V <sub>GT</sub>	On-state voltage	$I_{T} = 20 \text{ A}$		-	1.2	1.5	V
V <sub>GT</sub>	Gate trigger voltage	$\dot{V}_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$		-	0.7	1.5	V
-	<b>_</b>	$V_{\rm D} = 400 \text{ V}; I_{\rm T} = 0.1 \text{ A}; T_{\rm i} = 125$	°C	0.25	0.4	-	V
I <sub>D</sub>	Off-state leakage current	$V_{\rm D} = V_{\rm DRM(max)}; T_{\rm j} = 125  ^{\circ}{\rm C}$		-	0.1	0.5	mA

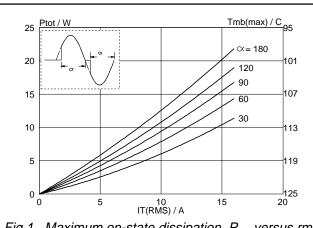
### **DYNAMIC CHARACTERISTICS**

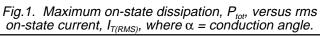
 $T_j = 25$  °C unless otherwise stated

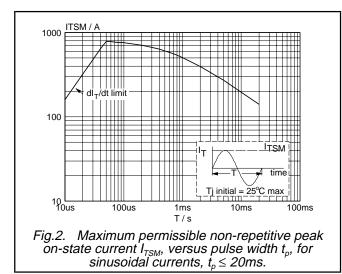
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV <sub>D</sub> /dt	Critical rate of rise of	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$	1000	4000	-	V/µs
dl <sub>com</sub> /dt	off-state voltage Critical rate of change of	exponential waveform; gate open circuit $V_{DM} = 400 \text{ V}; \text{ T}_{j} = 125 \text{ °C}; \text{ I}_{T(RMS)} = 16 \text{ A};$	-	28	-	A/ms
t <sub>gt</sub>	commutating current Gate controlled turn-on time	without snubber; gate open circuit $I_{TM} = 20 \text{ A}; V_D = V_{DRM(max)}; I_G = 0.1 \text{ A};$ $dI_G/dt = 5 \text{ A}/\mu \text{s}$	-	2	-	μs

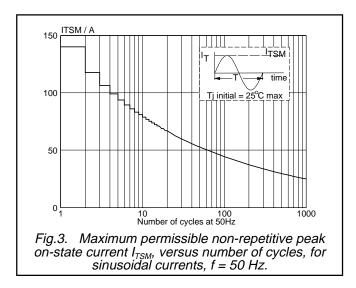
**<sup>2</sup>** Device does not trigger in the T2-, G+ quadrant.

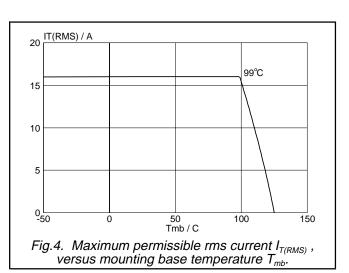
# BTA216 series B











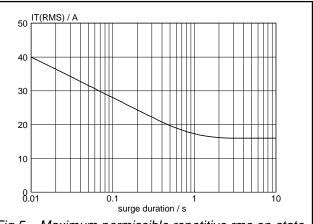
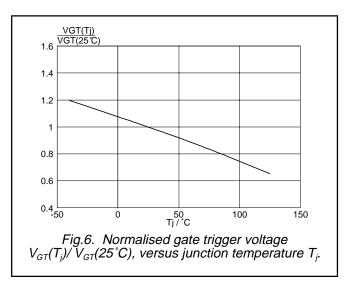
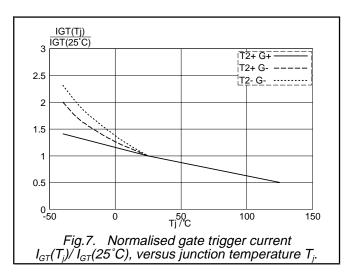
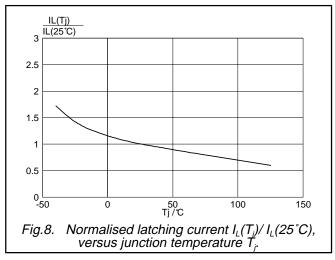


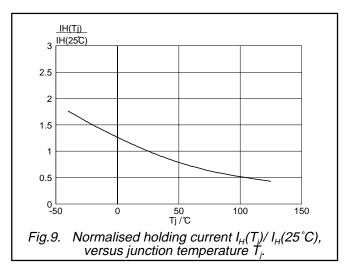
Fig.5. Maximum permissible repetitive rms on-state current  $I_{T(RMS)}$ , versus surge duration, for sinusoidal currents, f = 50 Hz;  $T_{mb} \le 99^{\circ}C$ .

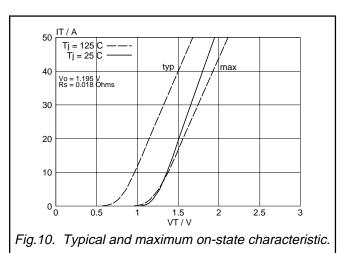


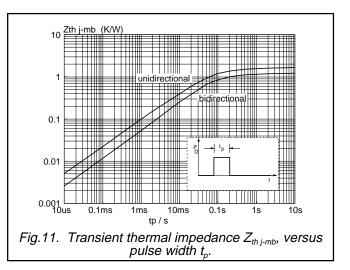
# BTA216 series B

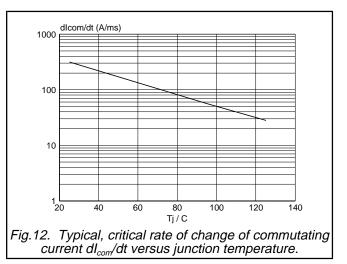








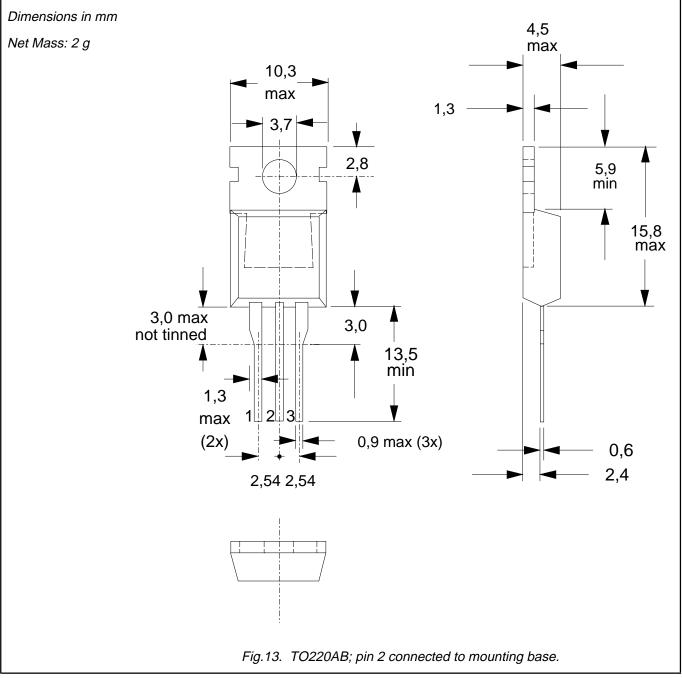




#### Product specification

# BTA216 series B

### **MECHANICAL DATA**



#### Notes

Refer to mounting instructions for TO220 envelopes.
Epoxy meets UL94 V0 at 1/8".

## BTA216 series B

### DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
or more of the limiting val operation of the device at	in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one ues may cause permanent damage to the device. These are stress ratings only and these or at any other conditions above those given in the Characteristics sections of uplied. Exposure to limiting values for extended periods may affect device reliability.
Application information	
Where application inform	ation is given, it is advisory and does not form part of the specification.
© Philips Electronics N	.V. 1997
All rights are reserved.	concoluction in whole or in part is prohibited without the prior written consent of the

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, it is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent or other industrial or intellectual property rights.

### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

Copyright © Each Manufacturing Company.

All Datasheets cannot be modified without permission.

This datasheet has been download from :

www.AllDataSheet.com

100% Free DataSheet Search Site.

Free Download.

No Register.

Fast Search System.

www.AllDataSheet.com